
#### Abstract

This report presents the effect of neutron displacement damage (NDD) on the UC1843B-SP device. The results show that devices remained within datasheet specifications up to $1 \times 10^{12} \mathrm{n} / \mathrm{cm}^{2}$. At $5 \times 10^{12}$ and 1 $\times 10^{13} \mathrm{n} / \mathrm{cm}^{2}$ some specifications went outside the range specified in the datasheet. A sample size of nine units was exposed to radiation testing per (MIL-STD-883, Method 1017 for Neutron Irradiation) and an additional unirradiated sample device was used for correlation. All devices used in the experiment were from lot date code 1828B. Electrical testing was performed at Texas Instruments before and after neutron irradiation using the production test program for UC1843B-SP.


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## 1 Overview

The UC1843B-SP is a current mode PWM controller. Start-up current is specified to be less than 0.5 mA and oscillator discharge is trimmed to 8.3 mA . During UVLO, the output stage can sink at least 10 mA at less than 1.2 V for VCC over 5 V . The devices are offered in an ultra small, thermally enhanced 10-pin ceramic flatpack package.
General device information and testing conditions are listed in Table 1.
Table 1. Overview Information

| TI Part Number | UC1843B-SP |
| :---: | :---: |
| Device Function | Current Mode PWM Controller |
| Die Name | SMEXARC1843VLS |
| Technology | JI1 |
| A/T Lot Number / Date Code | 1828 B |
| Unbiased Quantity Tested | 9 |
| Exposure Facility | VPT Rad |
| Neutron Fluence (1-MeV equivalent) | $1.0 \times 10^{12}, 5.0 \times 10^{12}, 1.0 \times 10^{13} \mathrm{n} / \mathrm{cm}^{2}$ |
| Irradiation Temperature | $25^{\circ} \mathrm{C}$ |

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Figure 1. UC1843B-SP Device

## 2 Test Procedures

The UC1843B-SP was electrically pre-tested using the production automated test equipment program. General test procedures were IAW MIL-STD-883, Method 1017 for Neutron Irradiation of UC1843B-SP.

Table 2. Neutron Irradiation Conditions

| Group | Sample Qty | Neutron Fluence (n/cm ${ }^{\mathbf{2}}$ ) | Bias |
| :---: | :---: | :---: | :---: |
| A | 3 | $1.0 \times 10^{12}$ | Unbiased |
| B | 3 | $5.0 \times 10^{12}$ | Unbiased |
| C | 3 | $1.0 \times 10^{13}$ | Unbiased |

## 3 Facility

Devices were exposed via fast neutron irradiation (FNI) at the University of Massachusetts's Lowell Research Reactor (UMLRR). The facility is designed to give a fast flux level $\geq 1011 \mathrm{n} / \mathrm{cm}^{2}-\mathrm{s}$, with relatively low thermal fluence and gamma dose rates. Samples with a cross-sectional area as large as 30 $\mathrm{cm}(12 \mathrm{in}) \times 30 \mathrm{~cm}$ ( 12 in ) and up to $15-\mathrm{cm}(6-\mathrm{in})$ thick can be irradiated. The fast neutron flux is designed to be nearly uniform over the $30-\mathrm{cm}(12-\mathrm{in}) \times 30-\mathrm{cm}(12-\mathrm{in})$ area facing the core, and the fast fluence variation through the sample thickness is minimized via a single $180^{\circ}$ rotation of the sample canister at the midpoint of the irradiation period. The FNI facility offers a significantly larger sample volume than previously available within the University of Massachusetts Lowell Research Reactor (UMLRR).
The fluences are calculated based on $1-\mathrm{MeV}$ equivalences.
Detailed information of the radiation facility is available at the following link:
www.uml.edu/docs/FNI\ Brochure_tcm18-90375.pdf

## 4 Results

At $5.0 \times 10^{12}$ and $1.0 \times 10^{13} \mathrm{n} / \mathrm{cm}^{2}$, some parametric measurements failed to remain within the range specified in the datasheet. All parametric measurements remained well within the UC1843B-SP Class V, radiation hardened current-mode PWM controller limits for $1.0 \times 10^{12} \mathrm{n} / \mathrm{cm}^{2}$ levels. The devices were no longer functional after exposure to $5.0 \times 10^{12}$ and $1.0 \times 10^{13} \mathrm{n} / \mathrm{cm}^{2}$ level when tested in the ATE. The full parameter list and graphs are found in Appendix A.
Table 3 lists the UC1843B-SP specification compliance matrix.

Table 3. UC1843B-SP Spec Table

| PARAMETER | TEST CONDITION | MIN | TYP | MAX | UNIT | TEST NUMBER |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| REFERENCE |  |  |  |  |  |  |
| Output voltage | $\mathrm{TJ}=25^{\circ} \mathrm{C}, \mathrm{IO}=1 \mathrm{~mA}$ | 4.85 | 5 | 5.1 | V | 1010.1, 1010.2 |
| Line regulation | VIN $=12$ to 25 V |  | 6 | 20 | mV | 1010.3 |
| Load regulation | $1 \mathrm{O}=1$ to 20 mA |  | 6 | 25 | mV | 1010.4 |
| Output noise voltage | $10 \mathrm{~Hz} \leq f \leq 10 \mathrm{kHz}, \mathrm{TJ}=25^{\circ} \mathrm{C}$ |  | 50 |  | uV | 1010.7 |
| Short-circuit output current |  | -30 | -100 | -180 | mA | 1010.6 |
| OSCILLATOR |  |  |  |  |  |  |
| Initial accuracy | $\mathrm{TJ}=25^{\circ} \mathrm{C}(4)$ | 47 | 52 | 57 | kHz | 1015.1, 1015.2 |
| Voltage stability | $\mathrm{VCC}=12$ to 25 V |  | 0.2\% | 1\% |  | 1015.3 |
| Discharge current | V pin $4=2 \mathrm{~V}(5)$, $\mathrm{TJ}=25^{\circ} \mathrm{C}$ | 7.8 | 8.3 | 8.8 | mA | 1015.7 |
| Discharge current | V pin $4=2 \mathrm{~V}(5)$, $\mathrm{TJ}=$ Full range | 7.5 |  | 8.8 |  | 1015.7 |
| ERROR AMPLIFIER |  |  |  |  |  |  |
| Input voltage | $\mathrm{VComp}=2.5 \mathrm{~V}$ | 2.45 | 2.50 | 2.55 | V | 1020.1 |
| Input bias current |  |  | -0.3 | -1 | uA | $\begin{gathered} 1020.6,1020.7, \\ 1020.8 \end{gathered}$ |
| Open-loop voltage gain | $\mathrm{VO}=2$ to 4 V | 65 | 90 |  | dB | 1020.9 |
| PSRR | $\mathrm{VCC}=12$ to 25 V | 60 | 70 |  | dB | 1020.10 |
| Output sink current | $\mathrm{VFB}=2.7 \mathrm{~V}$, VComp $=1.1 \mathrm{~V}$ | 2 | 6 |  | mA | 1020.5 |
| Output source current | $\mathrm{VFB}=2.3 \mathrm{~V}, \mathrm{VComp}=5 \mathrm{~V}$ | -0.5 | -0.8 |  | mA | 1020.4 |
| High-level output voltage | $\mathrm{VFB}=2.3 \mathrm{~V}, \mathrm{RL}=15 \mathrm{k} \Omega$ to ground | 5 | 6 |  | V | 1020.2 |
| Low-level output voltage | $\mathrm{VFB}=2.7 \mathrm{~V}, \mathrm{RL}=15 \mathrm{k} \Omega$ to VREF |  | 0.7 | 1.1 | V | 1020.3 |
| CURRENT SENSE |  |  |  |  |  |  |
| Gain(6) (7) |  | 2.85 | 3 | 3.15 | V/V | 1025.2 |
| Maximum input signal | $\mathrm{VComp}=5 \mathrm{~V}(6)$ | 0.9 | 1 | 1.1 | V | 1025.3 |
| Input bias current |  |  | -2 | -10 | uA | 1025.1 |
| Delay to output | VISENSE $=0$ to $2 \mathrm{~V}(2)$ |  | 150 | 300 | ns | 1025.4 |
| OUTPUT |  |  |  |  |  |  |
| Output low-level voltage | ISINK = 20 mA |  | 0.1 | 0.4 | V | 1030.6 |
|  | ISINK = 200 mA |  | 1.5 | 2.2 |  | 1030.7 |
| Output high-level voltage | ISOURCE $=-20 \mathrm{~mA}$ | 13 | 13.5 |  | V | 1030.1, |
|  | ISOURCE $=-200 \mathrm{~mA}$ | 12 | 13.5 |  |  | 1030.2 |
| Rise time | $\mathrm{CL}=1 \mathrm{nF}, \mathrm{TJ}=25^{\circ} \mathrm{C}(2)$ |  | 50 | 150 | ns | 1030.9 |
| Fall time | $\mathrm{CL}=1 \mathrm{nF}, \mathrm{TJ}=25^{\circ} \mathrm{C}$ (2) |  | 50 | 150 | ns | 1030.10 |
| UVLO saturation | $\mathrm{VCC}=5 \mathrm{~V}$, ISINK $=10 \mathrm{~mA}$ |  | 0.7 | 1.2 | V | 1030.5 |
| UNDERVOLTAGE LOCKOUT |  |  |  |  |  |  |
| Start threshold |  | 7.8 | 8.4 | 9 | V | 1035.1 |
| Minimum operation voltage after turnon |  | 7 | 7.6 | 8.2 | V | 1035.2 |

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Table 3. UC1843B-SP Spec Table (continued)

| PARAMETER | TEST CONDITION | MIN | TYP | MAX | UNIT | TEST NUMBER |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PWM |  |  |  |  |  |  |
| Maximum duty cycle |  | 94\% | 96\% | 100\% |  | 1030.11, 1030.12 |
| Minimum duty cycle |  |  |  | 0\% |  | 1030.13 |
| TOTAL STANDBY CURRENT |  |  |  |  |  |  |
| Start-up current |  |  | 0.3 | 0.5 | mA | 1005.1 |
| Operating supply current | VFB $=$ VISENSE $=0 \mathrm{~V}$ |  | 11 | 17 | mA | 1005.2, 1005.3 |
| VCC Zener voltage | ICC $=25 \mathrm{~mA}$ | 30 | 34 |  | V | 1035.4 |

## Test Results

Delta Threshold
10.00\%

NDD Report
Device Name









NDD Report
Device Name










NDD Report
Device Name















NDD Report
Device Name









NDD Report
Device Name




NDD Report
Device Name




NDD Report
Device Name



NDD Report
Device Name



1030.12_Max DC @ vCC=30V






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